

D1P6-3

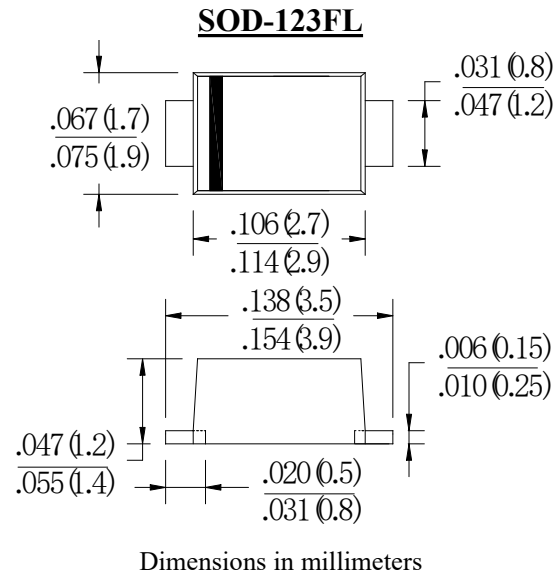
1.0AMP. SURFACE MOUNT GENERAL PURPOSE SILICON RECTIFIERS

FEATURES

- Glass passivated device
- Ideal for surface mounted applications
- Low reverse leakage
- Metallurgically bonded construction
- High temperature soldering guaranteed:
250°C/10 seconds at terminals.

MECHANICAL DATA

- Case: JEDEC SOD-123FL, molded plastic over passivated chip
- Terminals: Solder Plated, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode end
- Mounting position: Any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Type Number	SYMBOL	D1P6-3	units
	marking	.D1P6	
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	1000	V
Maximum RMS Voltage	V_{RMS}	700	V
Maximum DC Blocking Voltage	V_{DC}	1000	V
Maximum Average Forward rectified Current at $T_L = 90^\circ\text{C}$ (Note 1)	$I_{F(AV)}$	1.0	A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I_{FSM}	30	A
Maximum Instantaneous forward Voltage at 1.0A DC	V_F	1.3	V
Maximum DC Reverse Current @ $T_J = 25^\circ\text{C}$ at rated DC blocking voltage @ $T_J = 125^\circ\text{C}$	I_R	5.0 200.0	μA
Reverse Recovery Time (Note 1)	T_{rr}	500	nS
MIN MAX		1200	
Typical Junction Capacitance (Note 2)	C_J	7	pF
Typical thermal resistance (Note 3)	$R_{(JA)}$	180	$^\circ\text{C} / \text{W}$
	$R_{(JC)}$	28	
Storage Temperature Range	T_{STG}	-55 to +150	$^\circ\text{C}$
Operation Temperature Range	T_J	-55 to +150	$^\circ\text{C}$

Note:

1. Test Condition: $I_f=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{RR}=0.25\text{A}$
2. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc
3. Measured on P.C.Board with $15.0 \times 15.0 \times 1.6\text{mm}$ Copper Pad Areas.

RATING AND CHARACTERISTIC CURVES

FIG.1-TYPICAL FORWARD CURRENT DERATING CURVE

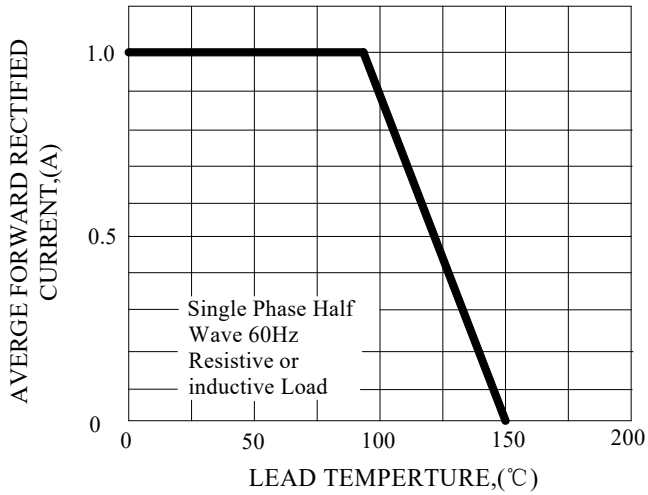


FIG.2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

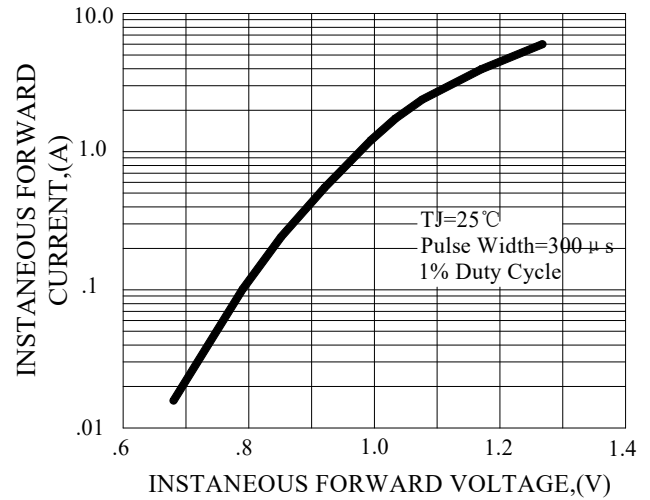


FIG.3-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

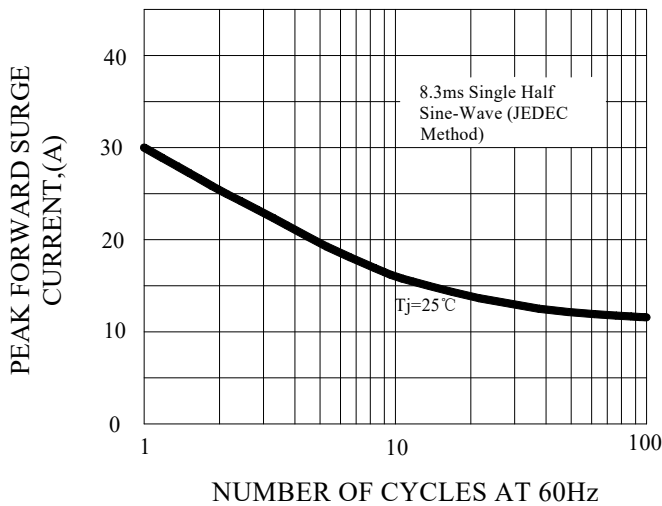


FIG.4-TYPICAL REVERSE CHARACTERISTICS

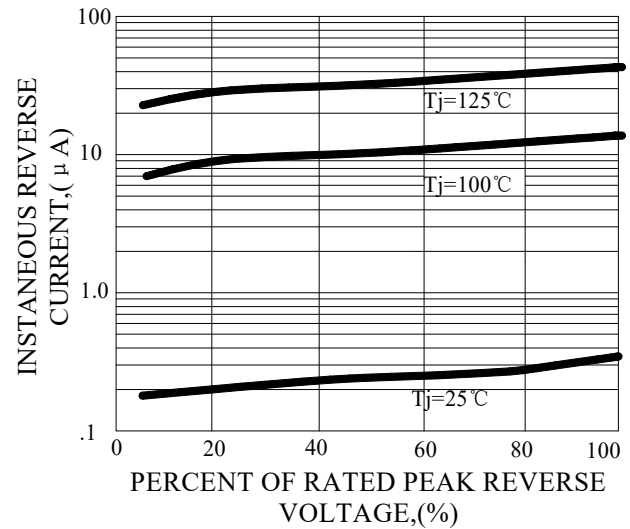
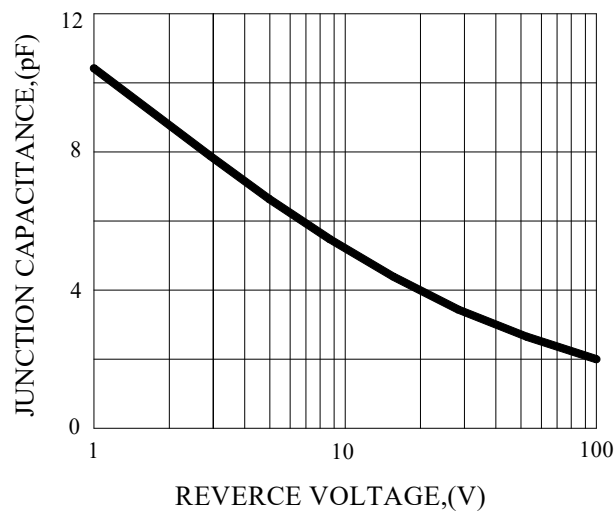
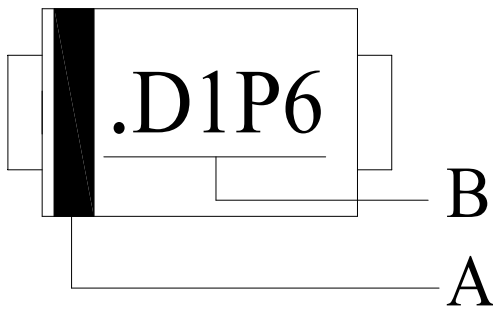


FIG.6-TYPICAL JUNCTION CAPACITANCE



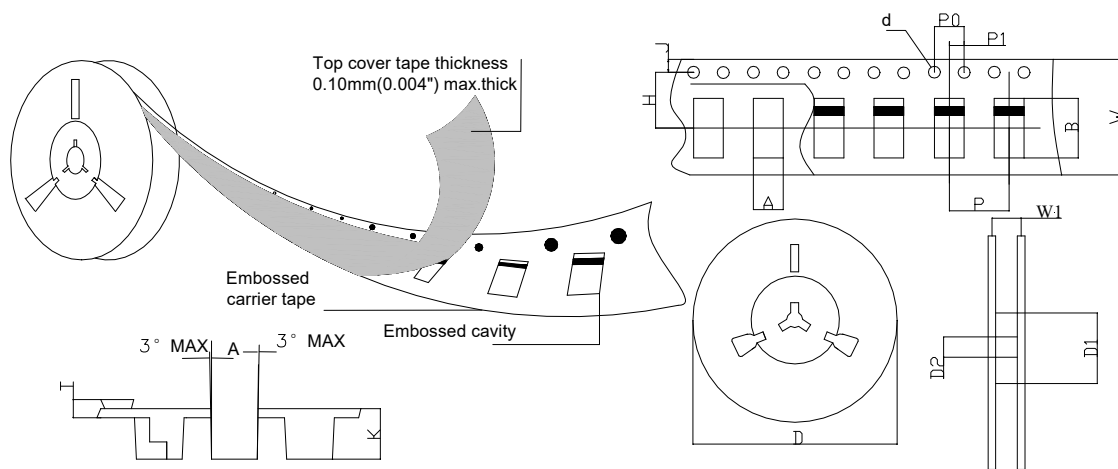
Marking and packaging illustration

1、Marking



SYMBOL	Explanation
A	Color Band Denotes Cathode
B	Product Name

2、Packaging



SPECIFICATIONS mm(inch)		PACKAGE	SPECIFICATIONS mm(inch)		PACKAGE
ITEM	SYM BOL	SOD-123FL	ITEM	SYM BOL	SOD-123FL
Carrier width	A	2.1(0.083)Max	Carrier depth	K	1.60±0.05
Carrier length	B	4.0(0.157)Max	Punch hole pitch	P	4.00±0.1
Sprocket hole	d	∅1.55(0.061)Typ	Sprocket hole pitch	P0	4.00(0.157)Typ
Reel outer diameter	D	177.8(7)Typ	Embossment center	P1	2.00(0.079)Typ
Reel inner diameter	D1	50.0(1.969)Min	Overall tape thickness	T	0.25(0.098)Typ
Feed hole diameter	D2	13.0(0.512)Typ	Tape width	W	8.15±0.1
Sprocket hole position	J	1.75(0.069)Typ	Reel width	W1	10.5(0.413)Min
Punch hole position	H	3.50(0.138)Typ			